

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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### **BD242/A/B/C**

# **Medium Power Linear and Switching Applications**

Complement to BD241/A/B/C respectively



1.Base 2.Collector 3.Emitter

### **PNP Epitaxial Silicon Transistor**

### Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage		
	: BD242	- 45	V
	: BD242A	- 60	V
	: BD242B	- 80	V
	: BD242C	- 100	V
V <sub>CER</sub>	Collector-Emitter Voltage		
	: BD242	- 55	V
	: BD242A	- 70	V
	: BD242B	- 90	V
	: BD242C	- 115	V
$V_{EBO}$	Emitter-Base Voltage	- 5	V
I <sub>C</sub>	Collector Current (DC)	- 3	Α
I <sub>CP</sub>	*Collector Current (Pulse)	- 5	Α
I <sub>B</sub>	Base Current	- 1	Α
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	40	W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 65 ~ 150	°C

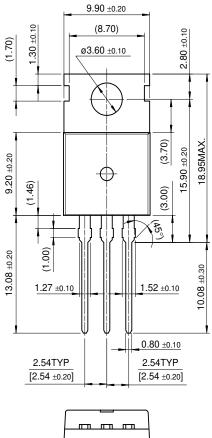
### **Electrical Characteristics** $T_C=25^{\circ}C$ unless otherwise noted

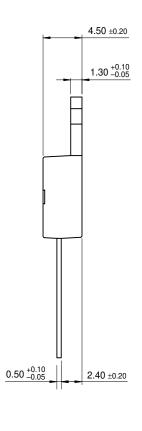
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V <sub>CEO</sub> (sus)	* Collector-Emitter Sustaining Voltage					
	: BD242	$I_C = -30 \text{mA}, I_B = 0$	- 45			V
	: BD242A		- 60			V
	: BD242B		- 80			V
	: BD242C		- 100			V
I <sub>CEO</sub>	Collector Cut-off Current : BD242/A	$V_{CE} = -30V, I_{B} = 0$			- 0.3	mA
	: BD242B/C	$V_{CE} = -60V, I_{B} = 0$			- 0.3	mA
I <sub>CES</sub>	Collector Cut-off Current : BD242	$V_{CE} = -45V, V_{BE} = 0$			- 0.2	mA
	: BD242A	$V_{CE} = -60V, V_{BE} = 0$			- 0.2	mA
	: BD242B	$V_{CE} = -80V, V_{BE} = 0$			- 0.2	mA
	: BD242C	$V_{CE} = -100V, V_{BE} = 0$			- 0.2	mA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = -5V, I_{C} = 0$			- 1	mA
h <sub>FE</sub>	* DC Current Gain	V <sub>CE</sub> = - 4V, I <sub>C</sub> = - 1A	25			
		$V_{CE} = -4V, I_{C} = -3A$	10			
V <sub>CE</sub> (sat)	* Collector-Emitter Saturation Voltage	I <sub>C</sub> = - 3A, I <sub>B</sub> = - 0.6A			- 1.2	V
V <sub>BE</sub> (on)	* Base-Emitter ON Voltage	$V_{CE} = -4V, I_{C} = -3A$			- 1.8	V
Pulse Test: PW=3	00μs, duty Cycle≤2% Pulsed	•		•	•	•

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# **Package Demensions**

# TO-220





10.00 ±0.20

Dimensions in Millimeters

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#### **Definition of Terms**

Datasheet Identification	Product Status	Definition
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